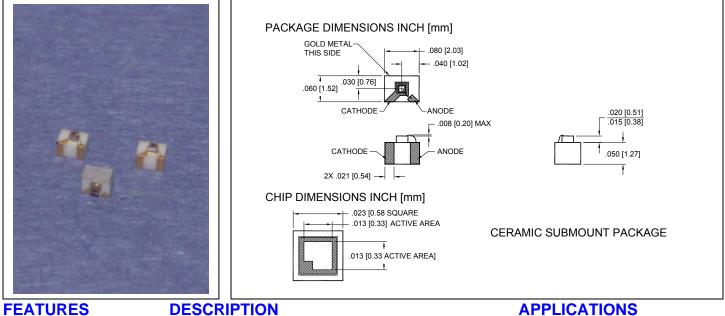


Blue Enhanced Photoconductive Silicon Photodiode **PDB-C122**



- Low noise ٠
- Blue enhanced ٠
- High shunt resistance ٠
- High response

The PDB-C122 is a blue enhanced PIN silicon photodiode in a photoconductive mode, packaged in a ceramic submount package.

- Instrumentation
- Industrial
- Medical

0.70 **(** 0.60 0.50

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0.00

250 300 350 400 450

SPECTRAL RESPONSE

500 550 600 600 770 770 770 770 880 880 880 900 950 950 950 91100

Wavelength (nm)

SYMBOL	PARAMETER	MIN	MAX	UNITS
V _{BR}	Reverse Voltage		75	V
T _{STG}	Storage Temperature	-65	+150	°C
To	Operating Temperature	-55	+125	°C
Ts	Soldering Temperature*		+240	°C

ABSOLUTE MAXIMUM RATING (TA)= 23°C UNLESS OTHERWISE NOTED

* 1/16 inch from case for 3 seconds max.

ELECTRO-OPTICAL CHARACTERISTICS RATING (TA)= 23°C UNLESS OTHERWISE NOTED

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	ТҮР	MAX	UNITS
I _{SC}	Short Circuit Current	H = 100 fc, 2850 K	1.2	1.5		μΑ
I _D	Dark Current	V _R = 5V		0.5	2.0	nA
R _{SH}	Shunt Resistance	V _R = 10 mV		500		MΩ
CJ	Junction Capacitance	V_R =5 V, f = 1 MHz		5	10	pF
λ range	Spectral Application Range	Spot Scan	350		1100	nm
R	Responsivity	λ = 450 nm V, V _R = 0 V	0.15	0.17		A/W
V _{BR}	Breakdown Voltage	I = 10 μA	50	100		V
NEP	Noise Equivalent Power	V _R =10V @ λ =950nm		9x10 ⁻¹⁵		W/ $\sqrt{_{\rm Hz}}$
tr	Response Time**	RL = 50 Ω,V _R = 0 V		190		- nS
		RL = 50 Ω,V _R = 10 V		13		

**Response time of 10% to 90% is specified at 660nm wavelength light.

Information in this technical datasheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.

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